# TECHNICAL INFORMATION

TENTATIVE Nov. 2017

# H13795 (R13435 Hybrid Assembly)

For Scintillation Counting, Fast Time Response 51 mm (2 inch) Diameter, Bialkali Photocathode, 10-stage, Head-on Type

## **GENERAL**

|                              | Parameter                   | Description / Value | Unit    |
|------------------------------|-----------------------------|---------------------|---------|
| Spectral Response            |                             | 300 to 650          | nm      |
| Wavelength of Catho          | de Radiant Sensitivity      | 420                 | nm      |
| Window Material              |                             | Borosilicate glass  | -       |
| Photocathode                 | Material                    | Bialkali            | -       |
| Photocathode                 | Minimum Effective Area      | 46                  | mm dia. |
| Dynode Structure / N         | umber of Stages             | Linear Focused / 10 | -       |
| Operating Ambient To         | emperature                  | 0 to +50            | °C      |
| Storage Temperature          |                             | 0 to +50            | °C      |
| Recommended Suppl<br>Cathode | y Voltage Between Anode and | -1750               | V       |

## **MAXIMUM RATINGS (Absolute Maximum Values)**

|  | Parameter | Value | Unit |  |
|--|-----------|-------|------|--|
| Supply Voltage Between Anode and Cathode |           | -2000 | V    |  |
| Average Anode Curre                      | nt        | 0.1   | mA   |  |

# CHARACTERISTICS (at 25 °C)

|                       | Parameter                          | Min. | Тур.       | Max. | Unit  |  |
|-----------------------|------------------------------------|------|------------|------|-------|--|
| Cothodo Sanaitivity   | Luminous (2856 K)                  | -    | 95         | -    | μA/lm |  |
| Cathode Sensitivity   | Blue Sensitivity Index (Cs 5-58)   | 9    | 10         | -    | 1     |  |
| Anode Sensitivity     | Luminous (2856 K)                  | 80   | 400        | -    | A/lm  |  |
| Gain                  |                                    | -    | $4.2x10^6$ | -    | -     |  |
| Anode Dark Current    | (After 30 min storage in darkness) | -    | 30         | 200  | nA    |  |
| Anode Pulse Rise Tin  | ne                                 | -    | 2.0        | -    | ns    |  |
| Electron Transit Time | 1                                  | 23   | -          | ns   |       |  |
| Transit Time Spread ( | 1                                  | 230  | -          | ps   |       |  |
| Pulse Linearity (+/-2 | -                                  | 30   | -          | mA   |       |  |

NOTE: Anode characteristics are measured with a voltage distribution ratio and supply voltage shown below.

## **VOLTAGE DISTRIBUTION RATIO**

| Electrodes | K   | G | Dy | y1 D | y2 D | у3 Г | y4 D | y5 I | )v6 | Dy7 | Dy8( | (Acc) | Dy9 | Dy1 | 0 | P |
|------------|-----|---|----|------|------|------|------|------|-----|-----|------|-------|-----|-----|---|---|
| Ratio      | 1.3 | 4 | 8  | 1.5  | 1.5  | 1    | 1    | 1    | 1   |     | 1    | 1     |     | 1   | 1 |   |

Supply Voltage: -1750 V, K: Cathode, Dy: Dynode, P: Anode, G: Grid, Acc: Accelerating electrode



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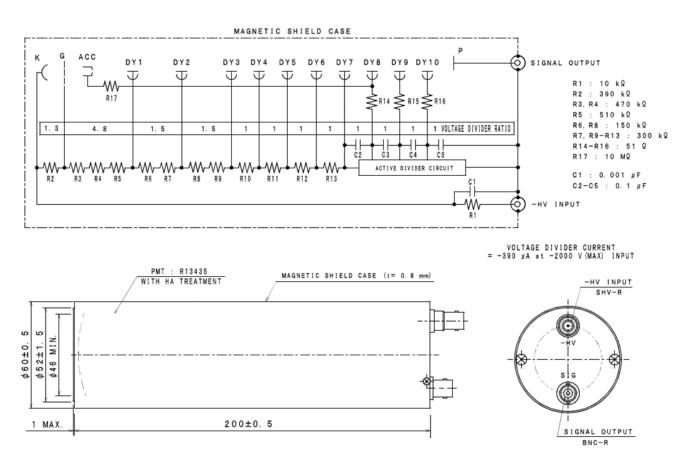


Figure 1: Dimensional Outline and Voltage Divider Circuit (Unit: mm)

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#### **NOTES**

The material in the H13795 contains Copper-Beryllium (CuBe) Alloy. Please follow the applicable regulations regarding disposal of hazardous materials and industrial wastes in your country, state, region or province.

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